

# **600V N-Channel MOSFET**

#### **FEATURES**

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information				
Device	Package	Marking		
TMA4N60H	TO-220F	A4N60H		
TMP4N60H	TO-220	P4N60H		
TMU4N60H	TO-251	U4N60H		
TMD4N60H	TO-252	D4N60H		

<b>Absolute Maximum Ratings</b> $T_C = 25^{\circ}C$ , unless otherwise noted						
B		Value				
Parameter	Symbol	TO-220F	TO-220	TO-251	TO-252	Unit
Drain-Source Voltage (V <sub>GS</sub> = 0V)	V <sub>DSS</sub>		60	00		V
Continuous Drain Current	I <sub>D</sub>	4		Α		
Pulsed Drain Current (note1)	I <sub>DM</sub>	16		Α		
Gate-Source Voltage	V <sub>GSS</sub>	±30		V		
Single Pulse Avalanche Energy (note2)	E <sub>AS</sub>	160		mJ		
Avalanche Current (note1)	I <sub>AR</sub>	4		Α		
Repetitive Avalanche Energy (note1)	E <sub>AR</sub>	20		mJ		
Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>D</sub>	36 75		W		
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150		°C		

Thermal Resistance						
Baramatar	Symbol	Value				
Parameter		TO-220F	TO-220	TO-251	TO-252	Unit
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	3.47		1.67		12/\\
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5		60		K/W

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### TMA4N60H,TMU4N60H,TMD4N60H,TMP4N60H

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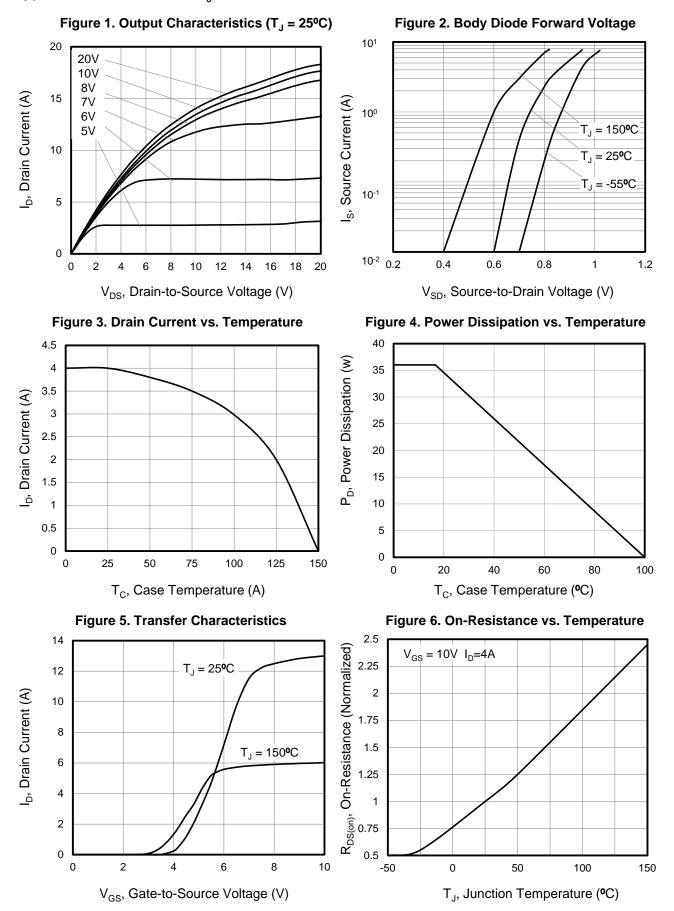
_		Value				
Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	600			٧
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μΑ
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		4.0	V
Drain-Source On-Resistance (Note3)	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 2.0A$		1.8	2.2	Ω
Dynamic				•	-	
Input Capacitance	C <sub>iss</sub>	V 0V		580		
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 25V,$		69.5		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		10.9		
Total Gate Charge	$Q_g$			15		
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 480V, I_{D} = 4.0A, V_{GS} = 10V$		2.5		nC
Gate-Drain Charge	$Q_{gd}$	- GS 101		7.5		
Turn-on Delay Time	t <sub>d(on)</sub>			12		
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 300V, I_{D} = 4.0A,$		22		
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 25 \Omega$		50		ns
Turn-off Fall Time	t <sub>f</sub>			48		
Drain-Source Body Diode Character	istics					
Continuous Body Diode Current	I <sub>s</sub>	T 0500			4	
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25 °C			16	А
Body Diode Voltage	$V_{SD}$	$T_J = 25^{\circ}\text{C}, I_{SD} = 4.0\text{A}, V_{GS} = 0\text{V}$			1.4	V
Reverse Recovery Time	t <sub>rr</sub>	$V_{GS} = 0V, I_{S} = 4.0A,$		250		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt =100A /µs		3.5		μC

#### **Notes**

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2.  $I_{AS}$  = 4A,  $V_{DD}$  = 50V,  $R_{G}$  = 25  $\Omega$ , Starting  $T_{J}$  = 25  $^{\circ}C$
- 3. Pulse Test: Pulse width ≤ 300µs, Duty Cycle ≤ 1%



### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted



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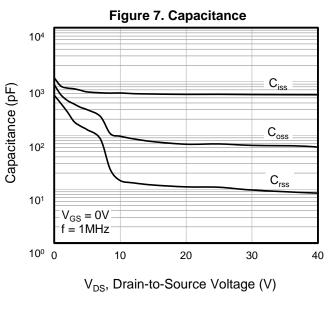


Figure 8. Gate Charge 10 V<sub>GS</sub>, Gate-to-Source Voltage (V)  $V_{DD} = 120V$ 8  $V_{DD} = 300 V$ 6  $V_{DD} = 480V$ 4 2 0 0 3 9 12 15 Q<sub>q</sub>, Total Gate Charge (nC)

Figure 9. Transient Thermal Impedance TO-220F

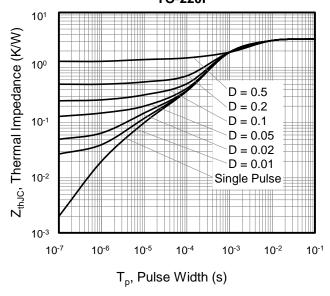
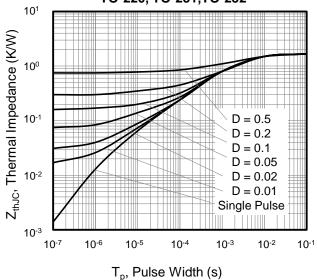


Figure 10. Transient Thermal Impedance TO-220, TO-251,TO-252



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Figure A: Gate Charge Test Circuit and Waveform

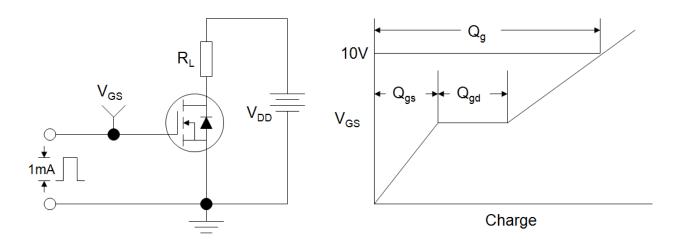


Figure B: Resistive Switching Test Circuit and Waveform

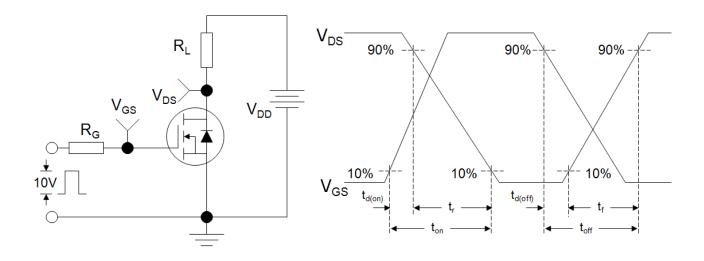
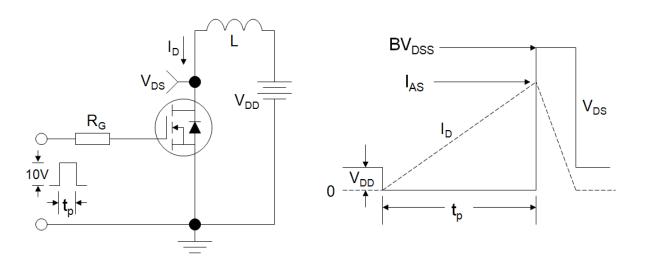
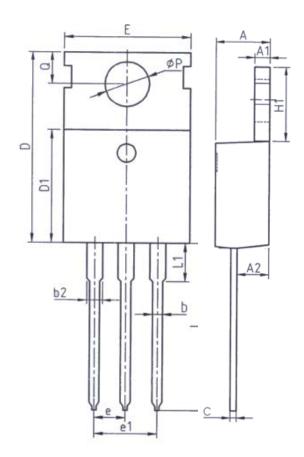


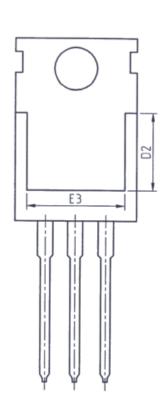
Figure C: Unclamped Inductive Switching Test Circuit and Waveform



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# **TO-220**

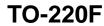


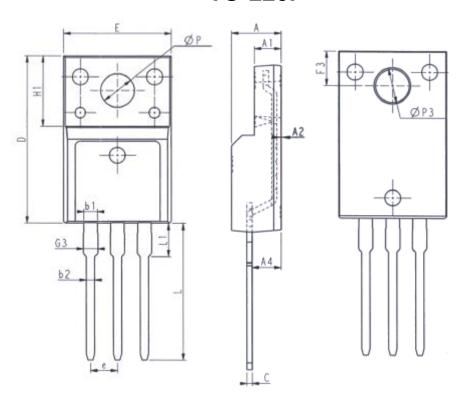


Unit: mm				
Symbol	Min.	Max.		
Α	4. 37	4. 77		
A1	1. 25	1. 45		
A2	2. 20	2. 60		
b	0. 70	0. 95		
b2	1. 17	1. 47		
С	0. 40	0. 65		
D	15. 10	16. 10		
D1	8. 80	9. 40		
D2	5. 50	_		

Unit: mm				
Symbol	Min.	Max.		
E	9. 70	10.30		
E3	7. 00	-		
е	2. 54BSC			
e1	5. 08	BBSC		
H1	6. 25	6. 85		
L	12. 75	13.80		
L1	-	3. 40		
P	3. 40	3. 80		
Q	2. 60	3. 00		

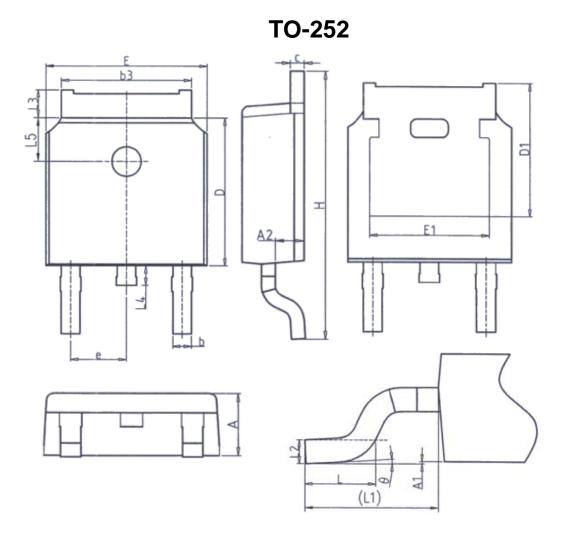






Unit: mm			l	Jnit: mn	1
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9. 96	10. 36	L	12. 68	13. 28
Α	4. 50	4. 90	L1	2. 93	3. 13
<b>A</b> 1	2. 34	2. 74	Р	3. 03	3. 38
A2	0. 30	0.60	Р3	3. 15	3. 65
A4	2. 56	2. 96	F3	3. 15	3. 45
С	0. 40	0. 65	G3	1. 25	1. 55
D	15. 57	16. 17	b1	1. 18	1. 43
H1	6. 70REF		b2	0. 70	0. 95
е	2. 54BSC				



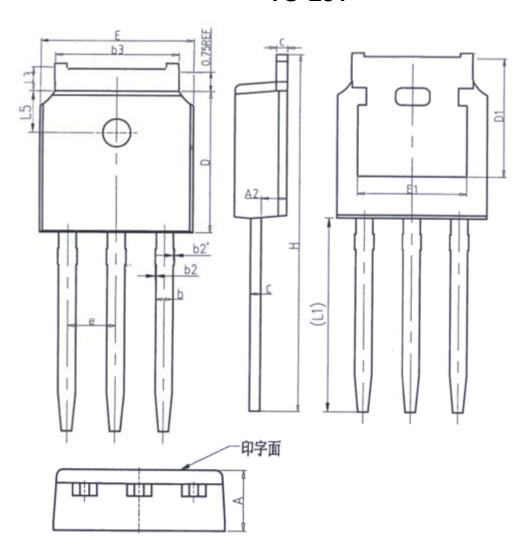


Unit: mm					
Symbol	Min.	Max.			
Α	2. 20	2. 40			
A1	0.00	0. 20			
A2	0. 97	1. 17			
b	0. 68	0. 90			
b3	5. 20	5. 50			
С	0. 43	0. 63			
D	5. 98	6. 22			
D1	D1 5. 30REF				
E	6. 40	6. 80			
E1	4. 63	-			

Unit: mm				
Symbol	Min.	Max.		
е	2. 28	6BSC		
Н	9. 40	10.50		
L	1. 38	1. 75		
L1	2. 90REF			
L2	0. 51	IBSC		
L3	0.88	1. 28		
L4	_	1.00		
L5	1. 65	1. 95		
θ	0°	8°		







Unit: mm					
Symbol	Min.	Max.			
Α	2. 20	2. 40			
A2	0. 97	1. 17			
b	0. 68	0.90			
b2	0.00	0.10			
b2′	0.00	0.10			
b3	5. 20	5. 50			
С	0. 43	0. 63			
D	5. 98	6. 22			

Unit: mm				
Symbol	Min.	Max.		
D1	5. 30REF			
E	6. 40	6. 80		
E1	4. 63	-		
е	2. 28	6BSC		
Н	16. 22	16. 82		
L1	9. 15	9. 65		
L3	0.88	1. 28		
L5	1. 65	1. 95		



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